

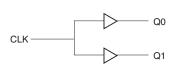
GENERAL DESCRIPTION

The 8302l is a low skew, 1-to-2 LVCMOS Fanout Buffer. The 8302l has a single ended clock input. The single ended clock input accepts LVCMOS or LVTTL input levels. The 8302l features a pair of LVCMOS outputs. The 8302l is characterized at full 3.3V for input $\rm V_{\rm DD}$, and mixed 3.3V and 2.5V for output operating supply modes ($\rm V_{\rm DDO}$). Guaranteedoutput and part-to-part skew characteristics make the 8302l ideal for clock distribution applications demanding well defined performance and repeatibility.

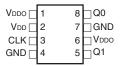
FEATURES

- 2 LVCMOS / LVTTL outputs
- LVCMOS / LVTTL clock input accepts LVCMOS or LVTTL input levels
- Maximum output frequency: 200MHz
- · Output skew: 40ps (typical)
- Part-to-part skew: 250ps (typical)
- · Small 8 lead SOIC package saves board space
- Full 3.3V or 3.3V core, 2.5V supply modes
- -40°C to 85°C ambient operating temperature
- · Lead-Free package fully RoHS compliant

BLOCK DIAGRAM



PIN ASSIGNMENT



8302I 8-Lead SOIC 3.8mm x 4.8mm, x 1.47mm package body M Package Top View



TABLE 1. PIN DESCRIPTIONS

Number	Name	Туре		Description
1, 6	$V_{\scriptscriptstyle DDO}$	Power		Output supply pins.
2	$V_{_{\mathrm{DD}}}$	Power		Core supply pin.
3	CLK	Input	Pulldown	LVCMOS / LVTTL clock input.
4,7	GND	Power		Power supply ground.
5	Q1	Output		Single clock output. LVCMOS / LVTTL interface levels.
8	Q0	Output		Single clock output. LVCMOS / LVTTL interface levels.

NOTE: Pulldown refers to internal input resistors. See Table 2, Pin Characteristics, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
_	Power Dissipation Capacitance	$V_{DD}, V_{DDO} = 3.465V$		22		pF
C _{PD}	(per output)	$V_{DD} = 3.465V, V_{DDO} = 2.625V$		16		pF
R _{PULLDOWN}	Input Pulldown Resistor			51		kΩ
R _{out}	Output Impedance			7		Ω



ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V_{DD} 4.6V

Inputs, V_{I} -0.5 V to V_{DD} + 0.5 V

Outputs, V_O -0.5V to V_{DDO} + 0.5V

Package Thermal Impedance, θ_{JA} 112.7°C/W (0 lfpm)

Storage Temperature, T_{STG} -65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 3A. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, Ta = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{DD}	Core Supply Voltage		3.135	3.3	3.465	V
V _{DDO}	Output Power Supply Voltage		3.135	3.3	3.465	V
I _{DD}	Power Supply Current				14	mA
I _{DDO}	Output Supply Current				5	mA

Table 3B. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{_{\mathrm{DD}}}$	Core Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I _{DD}	Power Supply Current				14	mA
I _{DDO}	Output Supply Current				5	mA

Table 3C. LVCMOS / LVTTL DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, Ta = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V _{IH}	Input High Voltage			2		V _{DD} + 0.3	V
V _{IL}	Input Low Voltage			-0.3		1.3	V
I _{IH}	Input High Current	CLK	$V_{DD} = V_{IN} = 3.465V$			150	μΑ
I _{IL}	Input Low Current	CLK	$V_{DD} = 3.465V, V_{IN} = 0V$	-5			μΑ
V	Output High Voltage		50Ω to $V_{DDO}/2$	2.6			V
V _{OH}			I _{OH} = -100μA	2.9			V
V	V _{oL} Output Low Voltage		50Ω to $V_{DDO}/2$			0.5	V
V _{OL}			I _{OL} = 100μA			0.2	V



 $\textbf{Table 3D. LVCMOS / LVTTL DC Characteristics, V}_{DD} = 3.3 \text{V} \pm 5\%, \text{ V}_{DDO} = 2.5 \text{V} \pm 5\%, \text{ Ta} = -40 ^{\circ}\text{C} \text{ to } 85 ^{\circ}\text{C}$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V _{IH}	Input High Voltage			2		V _{DD} + 0.3	V
V _{IL}	Input Low Voltage			-0.3		1.3	V
I _{IH}	Input High Current	CLK	$V_{DD} = V_{IN} = 3.465V$			150	μΑ
I	Input Low Current	CLK	$V_{DD} = 3.465V, V_{IN} = 0V$	-5			μA
\ <u></u>	Output High Voltage		50Ω to $V_{_{ m DDO}}/2$	1.8			V
V _{OH}			I _{OH} = -100μA	2.2			V
V	Output Low Voltage		50Ω to $V_{\tiny DDO}/2$			0.5	V
V _{OL}			I _{OL} = 100μA			0.2	V

Table 4A. AC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40$ °C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				200	MHz
tp _{LH}	Propagation Delay, Low-to-High; NOTE 1	<i>f</i> ≤ 200MHz	1.9	2.35	2.8	ns
tsk(o)	Output Skew; NOTE 2, 4			40	105	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 4			250	800	ps
t _R	Output Rise Time	20% to 80%	300		800	ps
t _F	Output Fall Time	20% to 80%	300		800	ps
odc	Output Duty Cyclo	<i>f</i> ≤ 133MHz	45		55	%
louc	Output Duty Cycle	133MHz < <i>f</i> ≤ 200MHz	40		60	%

Parameters measured at f_{MAX} unless otherwise noted. NOTE 1: Measured from $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO}/2.

NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{\rm DDO}/2$.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

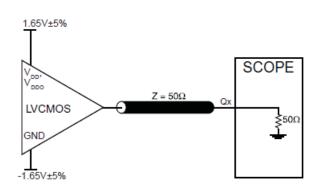
Table 4B. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, Ta = -40°C to 85°C

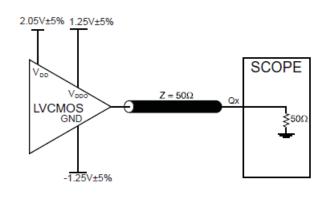
Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				200	MHz
tp _{LH}	Propagation Delay, Low-to-High; NOTE 1	<i>f</i> ≤ 200MHz	2.3		3.3	ns
tsk(o)	Output Skew; NOTE 2, 4				110	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 4			250	800	ps
t _R	Output Rise Time	20% to 80%	250		650	ps
t _F	Output Fall Time	20% to 80%	250		650	ps
odc Output Duty Cycle		<i>f</i> ≤ 133MHz	45		55	%
louc	Output Duty Cycle	133MHz < <i>f</i> ≤ 200MHz	40		60	%

See Table 4A above for notes.

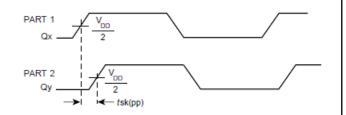


PARAMETER MEASUREMENT INFORMATION

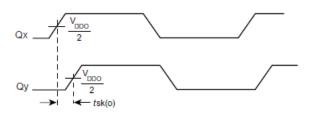




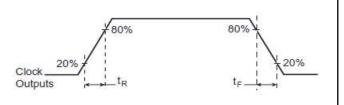
3.3V CORE/3.3V OUTPUT LOAD AC TEST CIRCUIT



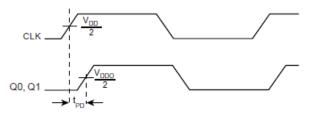




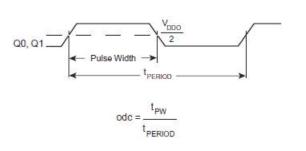
PART-TO-PART SKEW



OUTPUT SKEW



OUTPUT RISE/FALL TIME



PROPAGATION DELAY

OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD



RELIABILITY INFORMATION

Table 5. $\theta_{\text{JA}} \text{vs. Air Flow Table for 8 Lead SOIC}$

θJA by Velocity (Linear Feet per Minute)

O200500Single-Layer PCB, JEDEC Standard Test Boards153.3°C/W128.5°C/W115.5°C/WMulti-Layer PCB, JEDEC Standard Test Boards112.7°C/W103.3°C/W97.1°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

TRANSISTOR COUNT

The transistor count for 8302l is: 322



PACKAGE OUTLINE - SUFFIX M FOR 8 LEAD SOIC

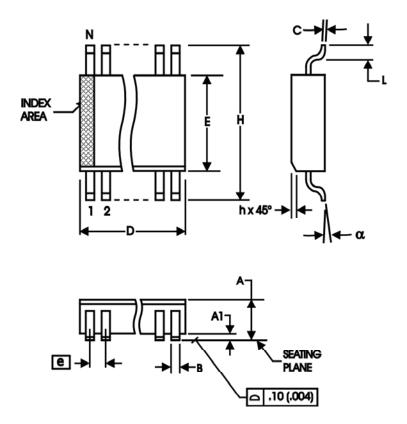


TABLE 6. PACKAGE DIMENSIONS

SYMBOL	Millim	neters
STWIBOL	MINIMUN	MAXIMUM
N	8	3
А	1.35	1.75
A1	0.10	0.25
В	0.33	0.51
С	0.19	0.25
D	4.80	5.00
Е	3.80	4.00
е	1.27 E	BASIC
Н	5.80	6.20
h	0.25	0.50
L	0.40	1.27
α	0°	8°

Reference Document: JEDEC Publication 95, MS-012



Table 7. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
8302AMILF	8302AMIL	8 lead "Lead Free" SOIC	Tube	-40°C to +85°C
8302AMILFT	8302AMIL	8 lead "Lead Free" SOIC	Tape and Reel	-40°C to +85°C



	REVISION HISTORY SHEET							
Rev	Table	Page	Description of Change	Date				
Α	T7	1 8	Features Section - added Lead-Free bullet. Ordering Information Table - added Lead-Free part number.	3/24/05				
А	T7	8 10	Updated datasheet's header/footer with IDT from ICS. Removed ICS prefix from Part/Order Number column. Added Contact Page.	7/29/10				
А	T7	8	Removed ICS from the part numbers where needed. Ordering Information - removed quantity from tape and reel. Deleted LF note below table. Updated data sheet header and footer.	3/4/16				





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